BLA6H0912-500

LDMOS avionics radar power transistor

Rev. 05 — 1 September 2015

AMPLEON

Product data sheet

1. Product profile

1.1 General description

500 W LDMOS power transistor intended for avionics transmitter applications in the 960 MHz to 1215 MHz range such as Mode-S, TCAS, JTIDS, DME and TACAN.

Table 1. Test information

Typical RF performance at $T_{\rm case}$ = 25 °C; t_p = 128 μ s; δ = 10 %; $I_{\rm Dq}$ = 100 mA; in a class-AB production test circuit.

Mode of operation	f	V _{DS}	P _L	Gp	η_{D}	t _r	t _f
	(MHz)	(V)	(W)	(dB)	(%)	(ns)	(ns)
pulsed RF	960 to 1200	50	450	17	50	20	6

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features and benefits

- Typical pulsed RF performance at a frequency of 960 MHz to 1215 MHz, a supply voltage of 50 V, an I_{Dq} of 100 mA, a t_p of 128 μs with δ of 10 %:
 - ◆ Output power = 450 W
 - ◆ Power gain = 17 dB
 - ◆ Efficiency = 50 %
- Easy power control
- Integrated ESD protection
- High flexibility with respect to pulse formats
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (960 MHz to 1215 MHz)
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

 A-band power amplifiers for radar applications in the 960 MHz to 1215 MHz frequency range

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	drain		,
2	gate		ئے
3	source		2 - 3 3 sym112

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	umber Package					
	Name	Description	Version			
BLA6H0912-500	-	flanged ceramic package; 2 mounting holes; 2 leads	SOT634A			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	100	V
V_{GS}	gate-source voltage		-0.5	+13	V
I _D	drain current		-	54	Α
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		-	200	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
Z _{th(j-c)}	transient thermal impedance from	T_{case} = 85 °C; P_L = 450 W		
	junction to case	$t_p = 32 \ \mu s; \ \delta = 2 \ \%$	0.03	K/W
		t_p = 128 μ s; δ = 10 %	0.08	K/W
		$t_p = 2400 \ \mu s; \ \delta = 6.4 \ \%$	0.2	K/W

6. Characteristics

Table 6. DC characteristics

 $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 2.7 \text{ mA}$	100	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 270 mA	1.3	1.8	2.2	V
I_{DSS}	drain leakage current	V_{GS} = 0 V; V_{DS} = 50 V	-	-	3.6	μА
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	53.5	64	-	Α
I_{GSS}	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	360	nA
g _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 405 mA	2.50	3.5	4.55	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 14.18 \text{ A}$	-	70	85	mΩ

Table 7. RF characteristics

Mode of operation: pulsed RF; f = 960 MHz to 1215 MHz; t_p = 128 μ s; δ = 10 %; RF performance at V_{DS} = 50 V; I_{Dq} = 100 mA; T_{case} = 25 °C; unless otherwise specified, in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
P_{L}	output power		-	450	-	W
V_{DS}	drain-source voltage	$P_{L} = 450 \text{ W}$	-	-	50	V
G_p	power gain	$P_{L} = 450 \text{ W}$	16	17	-	dB
RLin	input return loss	$P_{L} = 450 \text{ W}$	7	11	-	dB
η_{D}	drain efficiency	$P_{L} = 450 \text{ W}$	45	50	-	%
$P_{droop(pulse)}$	pulse droop power	$P_{L} = 450 \text{ W}$	-	0	0.3	dB
t _r	rise time	$P_{L} = 450 \text{ W}$	-	20	50	ns
t _f	fall time	$P_{L} = 450 \text{ W}$	-	6	50	ns

6.1 Ruggedness in class-AB operation

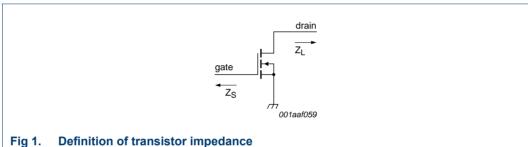
The BLA6H0912-500 is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: f = 960 MHz, 1030 MHz, 1090 MHz or 1215 MHz. V_{DS} = 50 V; I_{Dq} = 100 mA; P_{L} = 450 W; t_{p} = 128 μ s; δ = 10 %.

7. Application information

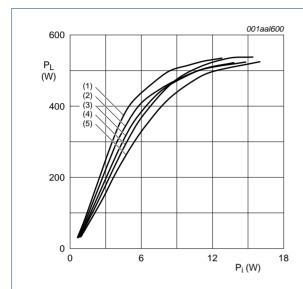
7.1 Impedance information

Table 8. **Typical impedance** Typical values per section unless otherwise specified.

f	Z _S	Z _L
MHz	Ω	Ω
960	1.36 – j1.45	1.49 – j1.48
1030	1.54 – j1.25	1.51 – j1.45
1090	1.67 – j1.22	1.36 – j1.47
1140	1.68 – j1.29	1.15 – j1.41
1215	1.43 – j1.42	0.79 – j1.17



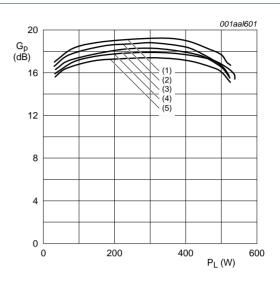
7.2 Performance curves



 V_{DS} = 50 V; I_{Dq} = 100 mA; t_p = 128 μ s; δ = 10 %.

- (1) f = 960 MHz
- (2) f = 1030 MHz
- (3) f = 1090 MHz
- (4) f = 1140 MHz
- (5) f = 1215 MHz

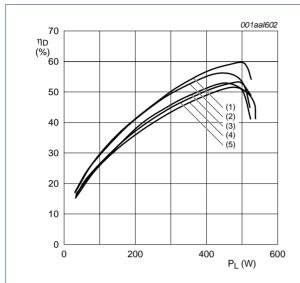
Fig 2. Load power as a function of input power; typical values



 V_{DS} = 50 V; I_{Dq} = 100 mA; t_p = 128 μ s; δ = 10 %.

- (1) f = 960 MHz
- (2) f = 1030 MHz
- (3) f = 1090 MHz
- (4) f = 1140 MHz
- (5) f = 1215 MHz

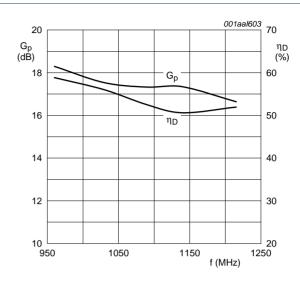
Fig 3. Power gain as a function of load power; typical values



 V_{DS} = 50 V; I_{Dq} = 100 mA; t_p = 128 $\mu s; \, \delta$ = 10 %.

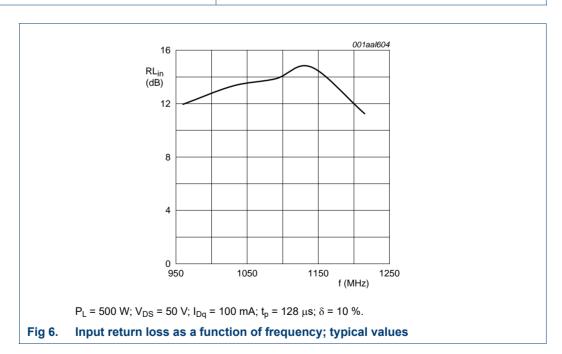
- (1) f = 960 MHz
- (2) f = 1030 MHz
- (3) f = 1090 MHz
- (4) f = 1140 MHz
- (5) f = 1215 MHz

Fig 4. Drain efficiency as a function of load power; typical values

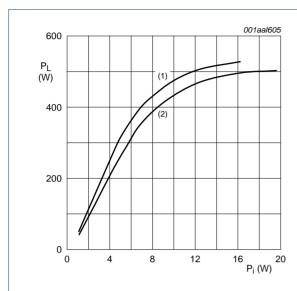


 V_{DS} = 50 V; I_{Dq} = 100 mA; t_p = 128 μ s; δ = 10 %.

Fig 5. Power gain and drain efficiency as function of frequency; typical values



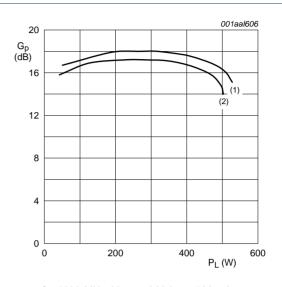
7.3 Curves measured under Mode-S ELM pulse-conditions



f = 1030 MHz; $V_{DS} = 50 \text{ V}$; $I_{Dq} = 100 \text{ mA}$.

- (1) $T_h = 25 \, ^{\circ}C$
- (2) $T_h = 65 \, ^{\circ}C$

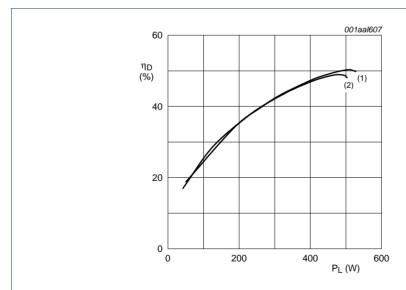
Fig 7. Load Power as a function of input power; typical values



f = 1030 MHz; $V_{DS} = 50 \text{ V}$; $I_{Dq} = 100 \text{ mA}$.

- (1) $T_h = 25 \, ^{\circ}C$
- (2) $T_h = 65 \, ^{\circ}C$

Fig 8. Power gain as a function of load power; typical values

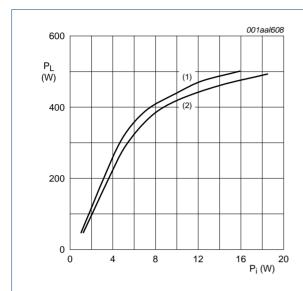


f = 1030 MHz; $V_{DS} = 50 \text{ V}$; $I_{Dq} = 100 \text{ mA}$.

- (1) $T_h = 25 \, ^{\circ}C$
- (2) $T_h = 65 \, ^{\circ}C$

Fig 9. Drain efficiency as function of load power; typical values

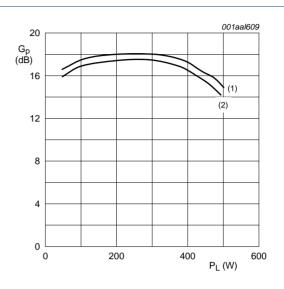
7.4 Curves measured under Mode-S interrogator pulse-conditions



f = 1030 MHz; $V_{DS} = 50 \text{ V}$; $I_{Dq} = 100 \text{ mA}$.

- (1) $T_h = 25 \, ^{\circ}C$
- (2) $T_h = 65 \, ^{\circ}C$

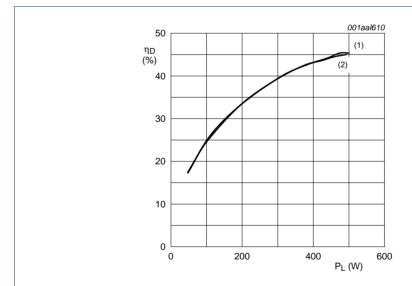
Fig 10. Load Power as a function of input power; typical values



f = 1030 MHz; $V_{DS} = 50 \text{ V}$; $I_{Dq} = 100 \text{ mA}$.

- (1) $T_h = 25 \, ^{\circ}C$
- (2) $T_h = 65 \, ^{\circ}C$

Fig 11. Power gain as a function of load power; typical values

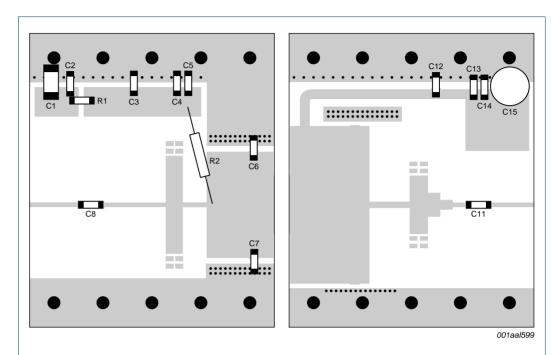


f = 1030 MHz; $V_{DS} = 50 \text{ V}$; $I_{Dq} = 100 \text{ mA}$.

- (1) $T_h = 25 \, ^{\circ}C$
- (2) $T_h = 65 \, ^{\circ}C$

Fig 12. Drain efficiency as function of load power; typical values

8. Test information



Printed-Circuit Board (PCB) material: Duroid 6006 with ϵ_r = 6.15 and thickness = 0.64 mm. See Table 9 for list of components.

Fig 13. Component layout

Table 9. List of components See *Figure* 13 for component layout.

Component	Description	Value	Remarks
C1, C3	multilayer ceramic chip capacitor	10 μF; 35 V	
C2, C3, C14	multilayer ceramic chip capacitor	39 pF	[1]
C4, C13	multilayer ceramic chip capacitor	1 nF	[1]
C6, C7	multilayer ceramic chip capacitor	6.8 pF	[2]
C5, C8, C11, C12	multilayer ceramic chip capacitor	82 pF	[2]
C15	electrolytic capacitor	47 μF; 63 V	
R1	SMD resistor	56 Ω	SMD 0603
R2	metal film resistor	51 Ω	

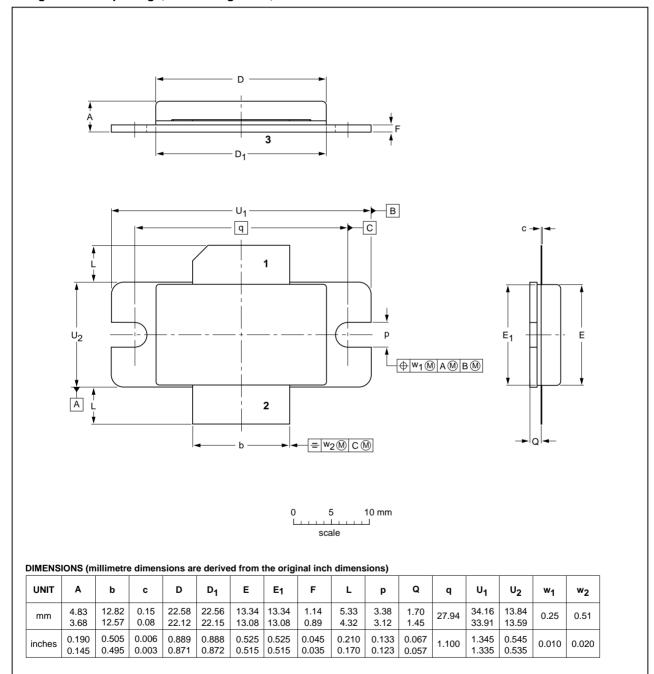
^[1] American Technical Ceramics type 100B or capacitor of same quality.

^[2] American Technical Ceramics type 800B or capacitor of same quality.

9. Package outline

Flanged ceramic package; 2 mounting holes; 2 leads

SOT634A



OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION		
SOT634A					-01-11-27 03-05-01	

Fig 14. Package outline SOT634A

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
DME	Distance Measuring Equipment
ELM	Extended Length Message
JTIDS	Joint Tactical Information Distribution System
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
Mode-S	Mode Select
RF	Radio Frequency
SMD	Surface Mounted Device
TACAN	TACtical Air Navigation
TCAS	Traffic Collision Avoidance System
VSWR	Voltage Standing-Wave Ratio

11. Revision history

Table 11. Revision history

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Document ID	Release date	Data sheet status	Change notice	Supersedes			
BLA6H0912-500_5	20150901	Product data sheet	-	BLA6H0912-500_4			
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. 						
	 Legal texts h 	ave been adapted to the new	company name where	appropriate.			
BLA6H0912-500_4	20100510	Product data sheet	-	BLA6H0912-500_3			
BLA6H0912-500_3	20100330	Product data sheet	-	BLA6H0912-500_2			
BLA6H0912-500_2	20100302	Product data sheet	-	BLA6H0912-500_1			
BLA6H0912-500_1	20090305	Objective data sheet	-	-			

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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